

# MEASUREMENT COMPARISONS BETWEEN OPTICAL AND MECHANICAL EDGES FOR A SILICON MICROMACHINED DIMENSIONAL CALIBRATION STANDARD

**26<sup>th</sup> Annual Meeting of ASPE**  
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1. Sandia National Laboratories
2. Micro Encoder Inc
3. Mitutoyo America Corporation



# Outline of Presentation

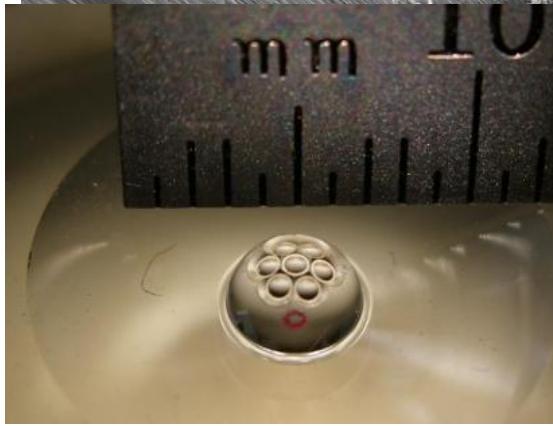
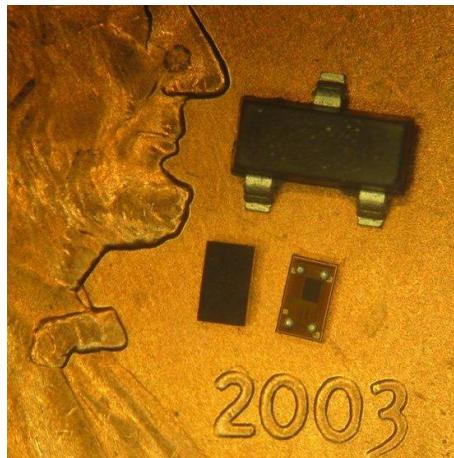
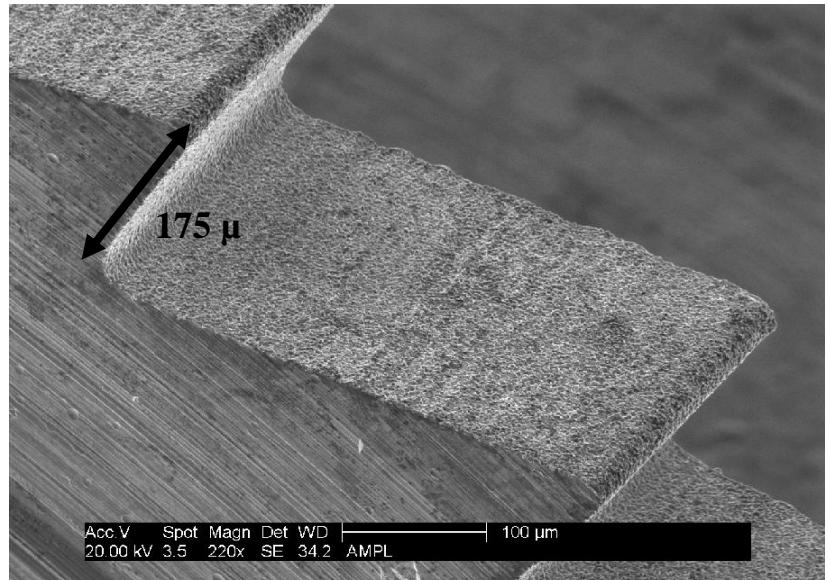
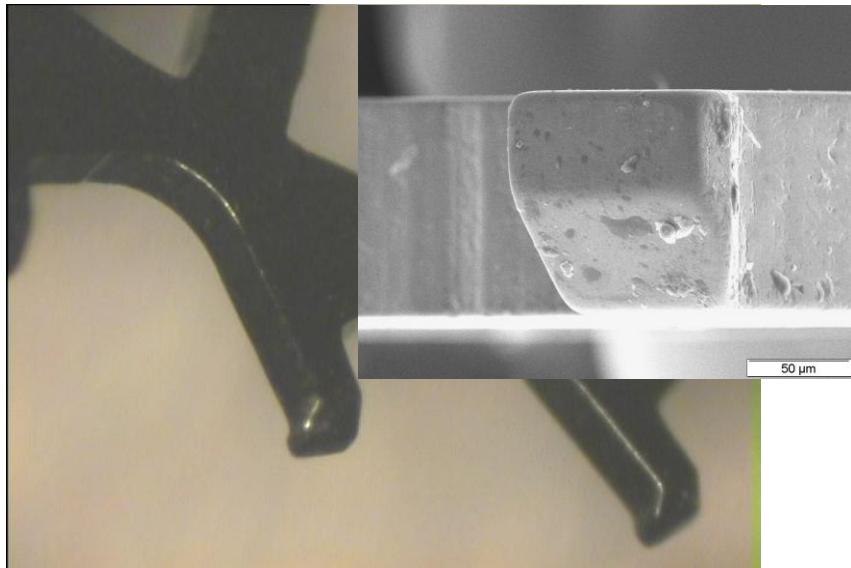
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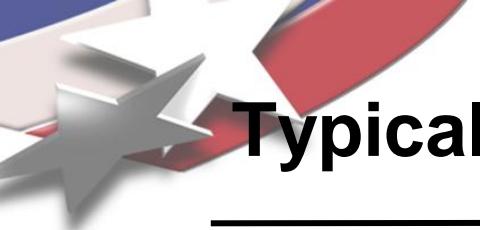
- Motivation for work: Inspection of mm-scale parts with  $\mu\text{m}$  to sub- $\mu\text{m}$  measurement uncertainty
- Development of bulk-micromachined silicon calibration standard, with a common mechanical (touch probe) and optical (vision) edge
- Experimental Results
- Conclusions



# Examples of Mesoscale Components

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# Typical Capabilities for Existing Systems

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- Vision system repeatability typically order of  $0.1\mu\text{m}$  (using averaging)
- Typical measurement uncertainties from various manufacturers and models (vision):
  - $1.5 + 4L/1000\ \mu\text{m}$
  - $0.5 + 2L/1000\ \mu\text{m}$
  - $1.0 + 2L/1000\ \mu\text{m}$
- Typical measurement uncertainties for Micro CMM's:
  - $0.3 + L/1000\ \mu\text{m}$
  - $0.25 + 1.5L/1000\ \mu\text{m}$
- Hybrid, or multi-sensor systems with both stylus & non-contact (vision) sensor



# How Do We Improve Calibration?

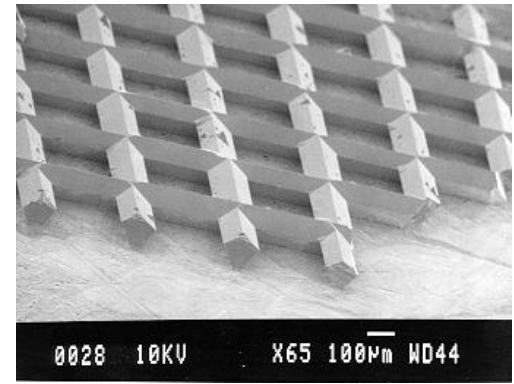
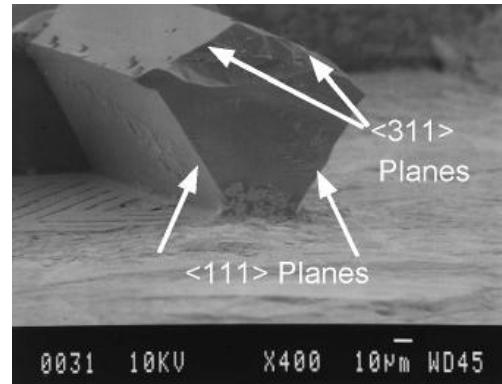
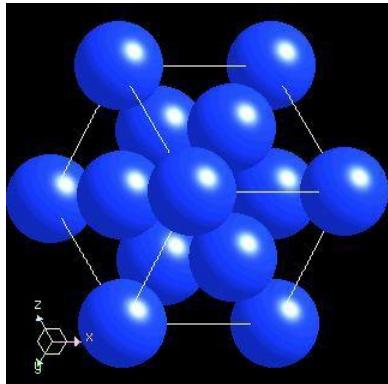
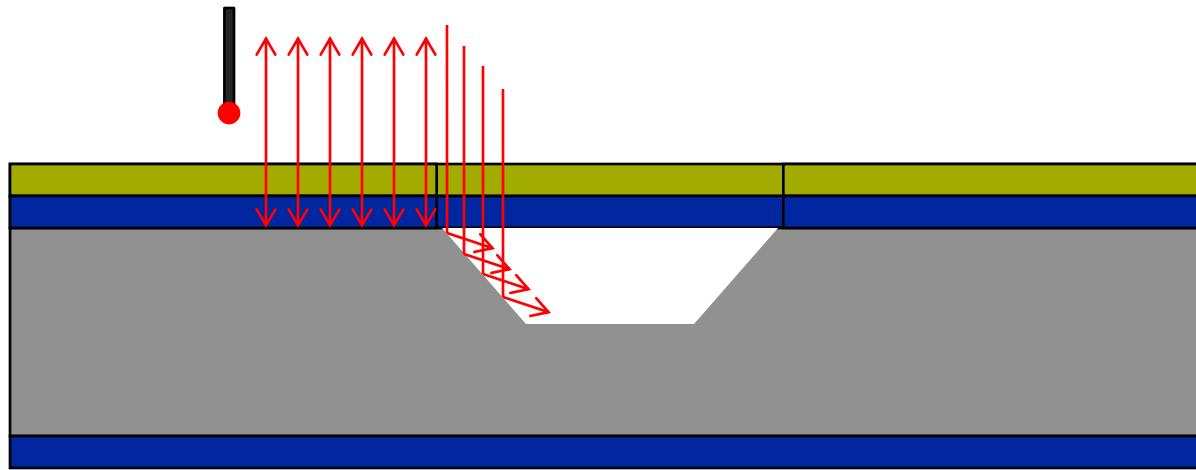
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- The accuracy of vision systems is typically limited by calibration artifact, not resolution:
  - Calibration artifact accuracy  $\sim 1\mu\text{m}$
  - System repeatability  $\sim 0.1\mu\text{m}$
- Can we design a better calibration tool?
- Can we make a calibration artifact that satisfies the needs for vision systems, micro CMM's, and multisensor systems?



# Si Bulk Micromachining

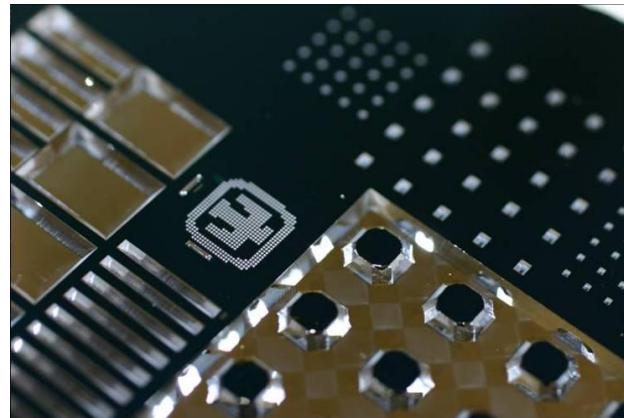
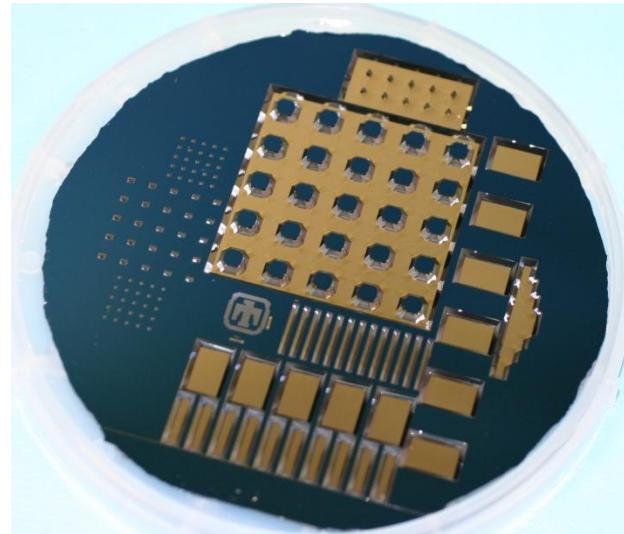
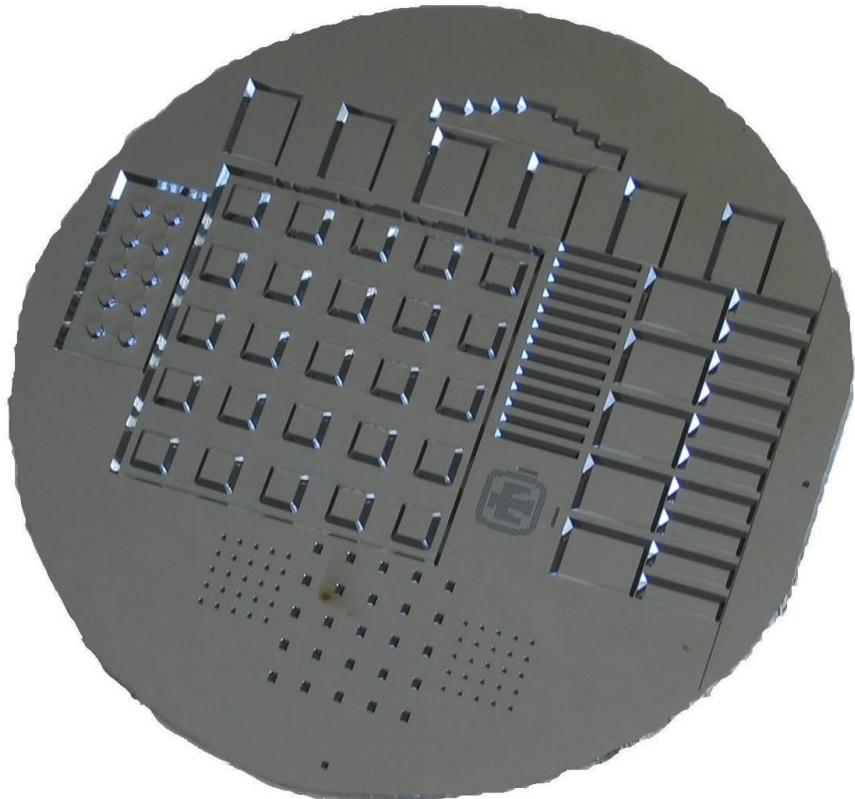
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# Initial Test Structures

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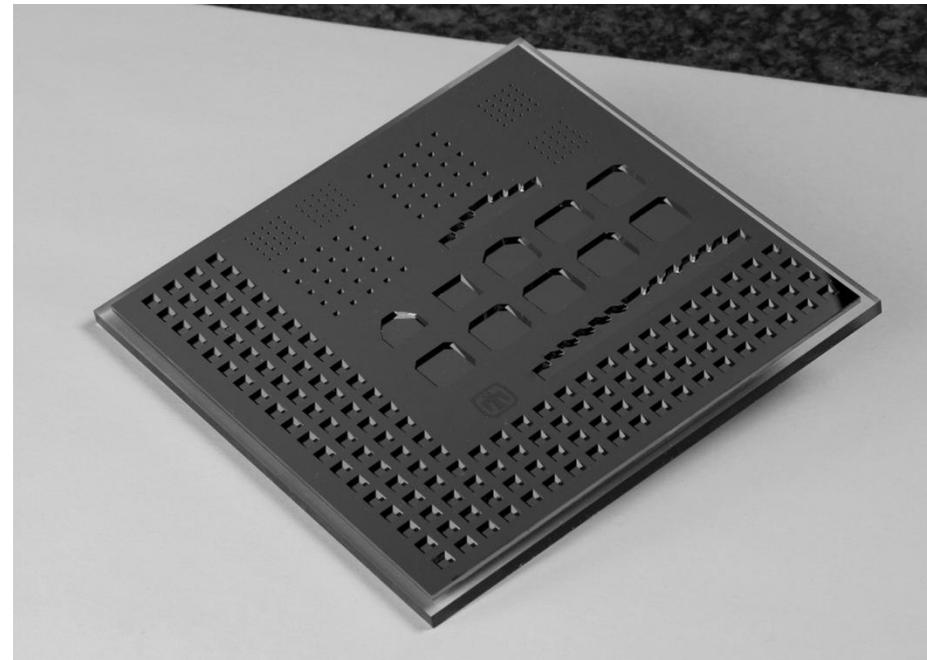
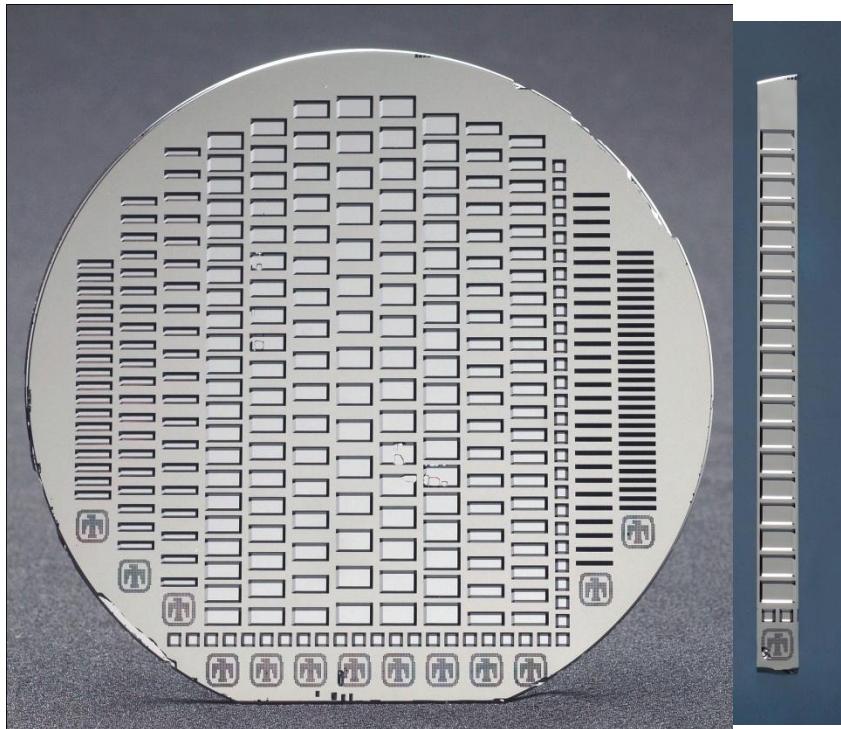




# Second Design Iteration

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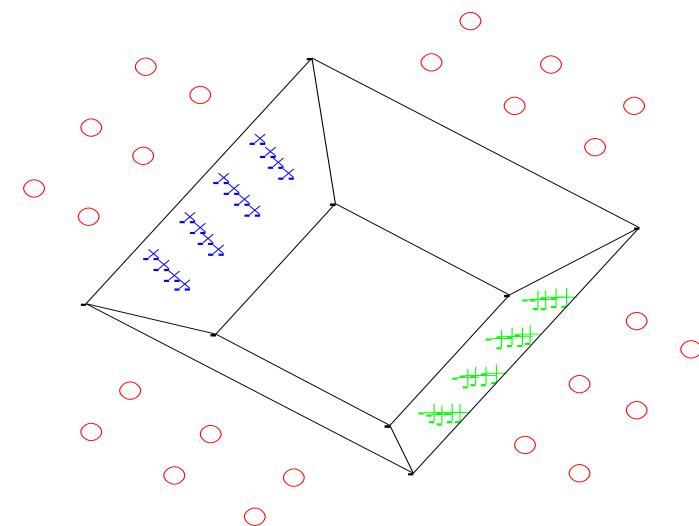
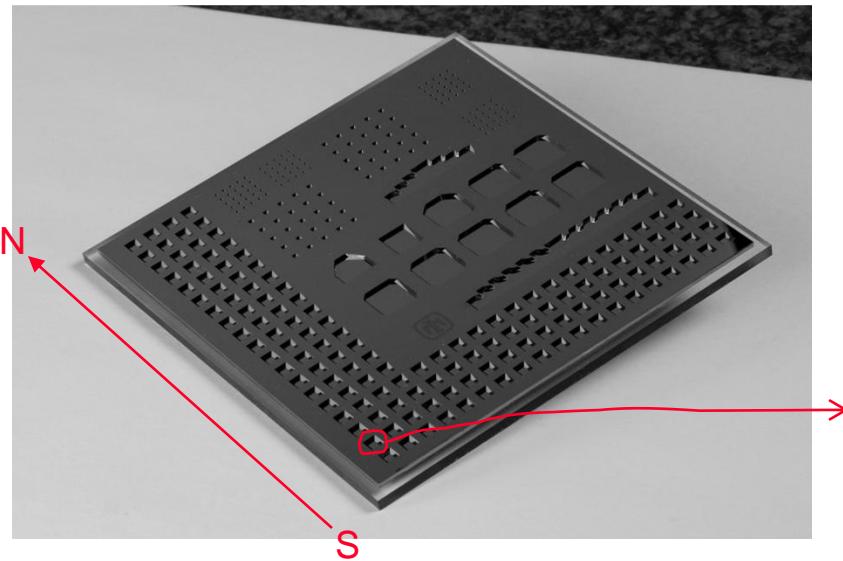
- Process improvement studies (etch optimization; mask alignment improvements)
- Two designs, based on user feedback (using 150 mm wafers)





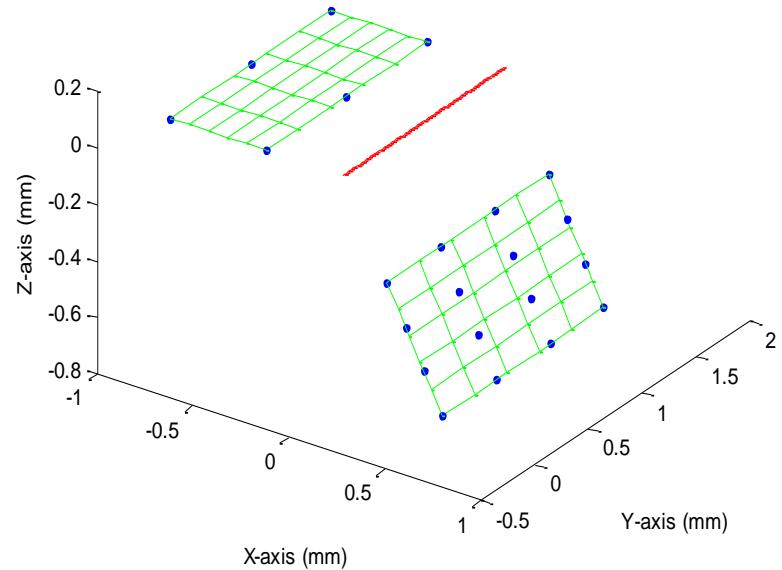
# Probing on CMM

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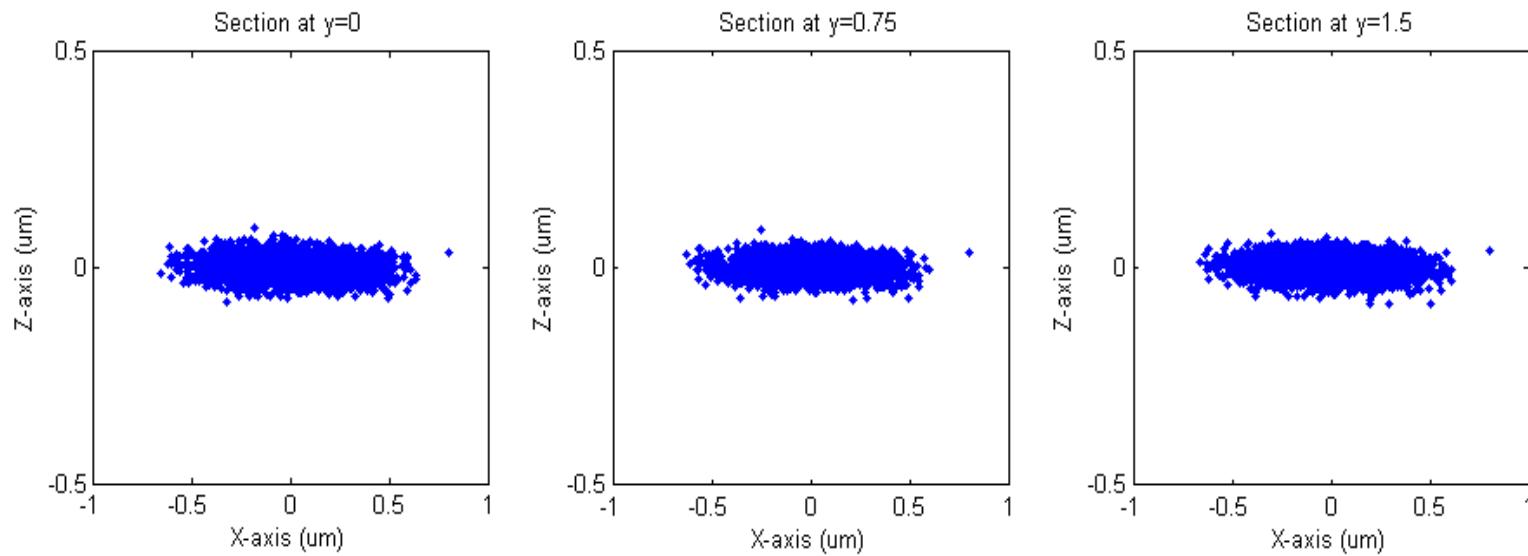


# Surface Roughness of Silicon Artifact

- Process optimization in alignment and etch parameters performed, but sidewalls are still not as smooth as top surfaces.
  - Top surfaces have combined form/roughness deviations  $\pm 100$  nm over 5 mm span
  - Etched sidewalls have combined form/roughness deviations  $\pm 600$  nm over a 5 mm span
- Form and roughness deviations may lead to greater uncertainty in the location of the plane or the projected intersection line (edge)
- Form and roughness deviations have minor effects on the location of the midpoint between two edges!



# Monte Carlo Simulations for Effects of Roughness



- Plots from 5000 simulated data sets, using statistics from actual CMM data  $\rightarrow 0.4 \mu\text{m}$  uncertainty at  $k=2$  for location of a single edge
- Note that roughness should not have an effect on the distance of the pitch between adjacent cavities

# Measurement Comparisons

- Leitz PMM-C-Infinity 12.10.6 at Sandia National Laboratories
- OGP Smartscope Apex at Sandia National Laboratories
- Mitutoyo QV Ultra at Micro Encoder Inc with a 25 X objective
- 2 Mitutoyo M-Nanocoord; one with UMAP and vision probing; other with long range ultralow scanning probe (LNP)
- Mitutoyo Formtracer CS-3100 at Mitutoyo America Corp, Aurora, IL

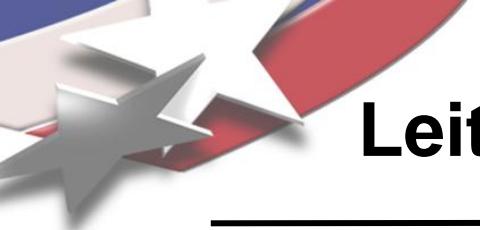




# Estimates of measurement uncertainty

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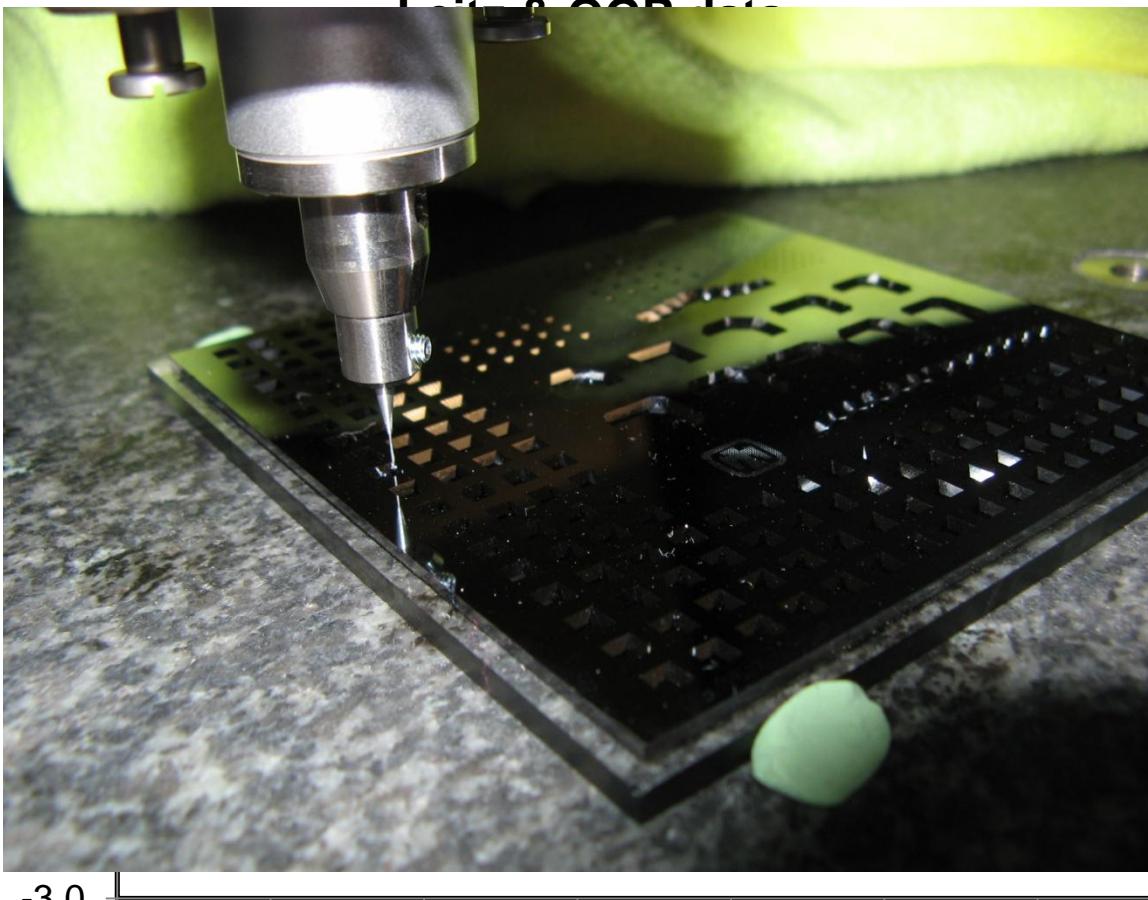
- Mainly type B, based on:
  - Simulation of roughness  $\rightarrow 0.4 \mu\text{m}$
  - MPE of equipment  $\rightarrow$  rectangular distribution
- Repeatability of measurements significantly smaller than type B evaluation
- We estimate: Larger of either  $0.4 \mu\text{m}$  or MPE converted from rectangular to normal at  $k=2$



# Leitz & OGP measurement results

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Measured Size - Design Size ( $\mu\text{m}$ )



-3.0

0

10

20

30

40

50

60

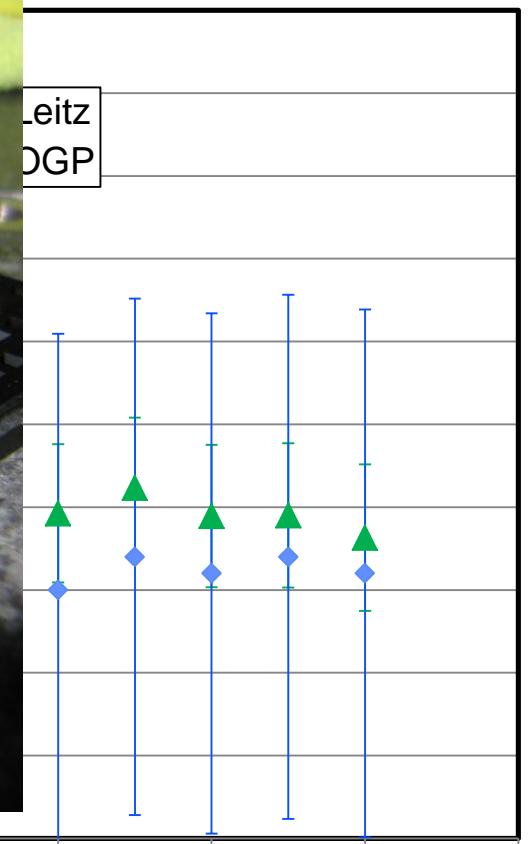
70

80

90

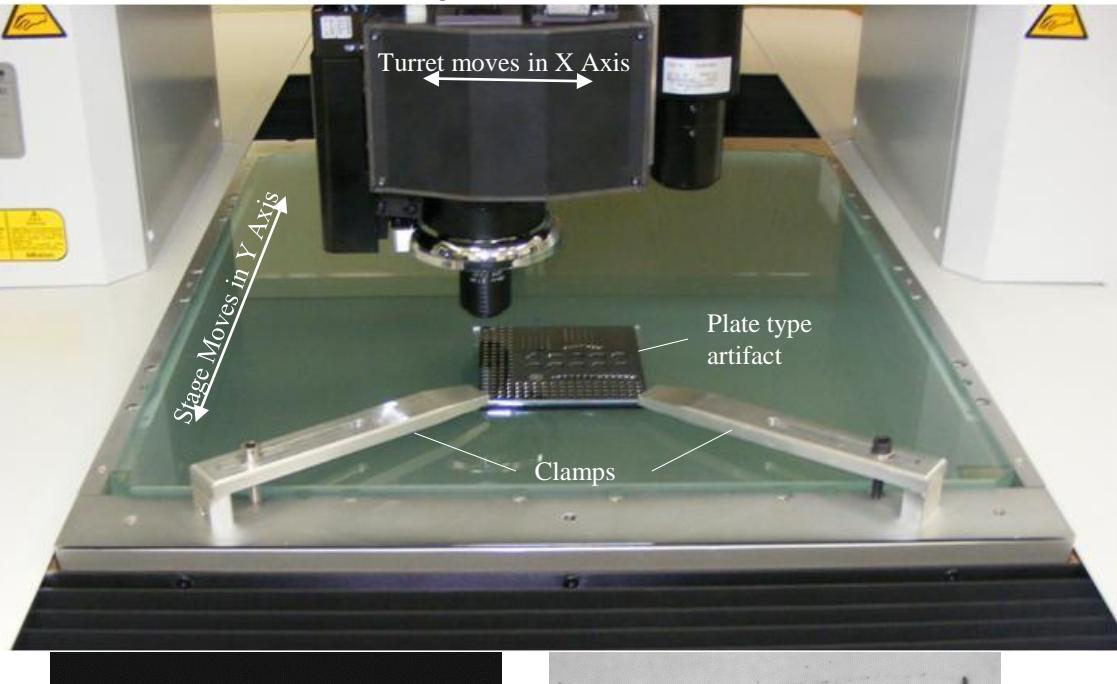
100

Position (mm)

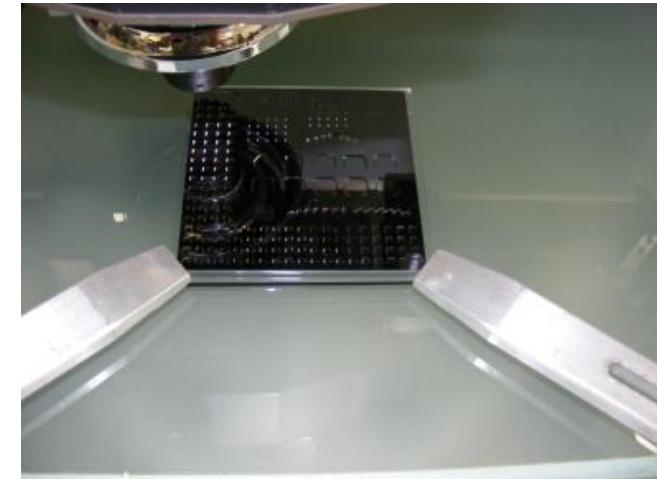


# MEI measured the plate type artifact with QV Ultra

## Measurement setup on QV Ultra



- 25 X objective, calibrated before measurements
- QV box tool used. Both rising edge and falling edge algorithm were tested
- QV Ultra machine was recently calibrated
- The artifact was attached to the QV stage in three different ways: Clamp, clay, resting (just placed on stage)



Artifact clamped to stage

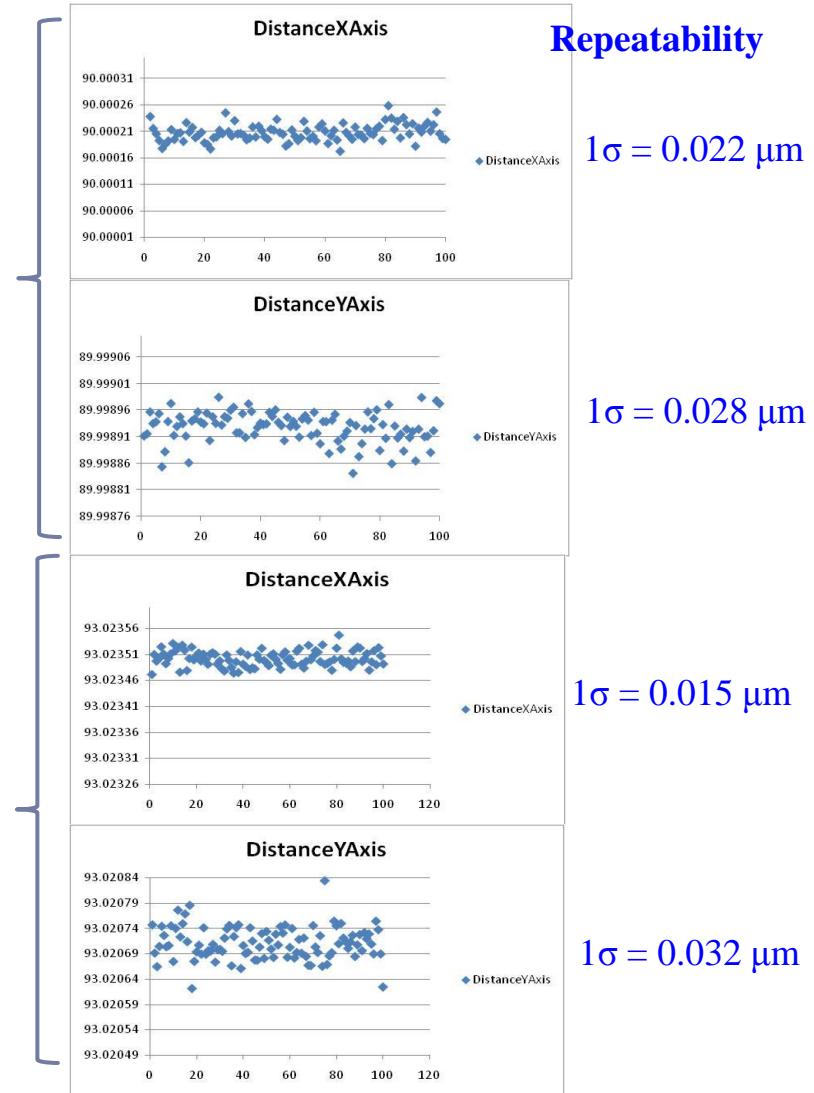
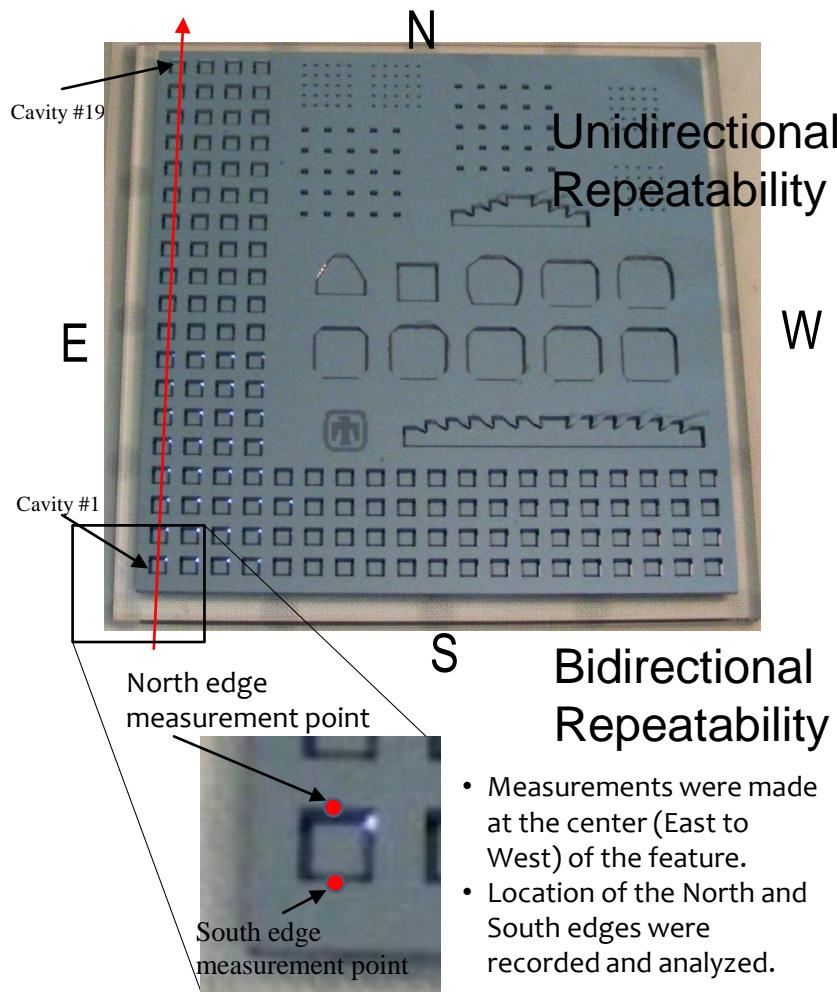


Artifact held with clay

# QV Ultra measurements at Micro Encoder Inc

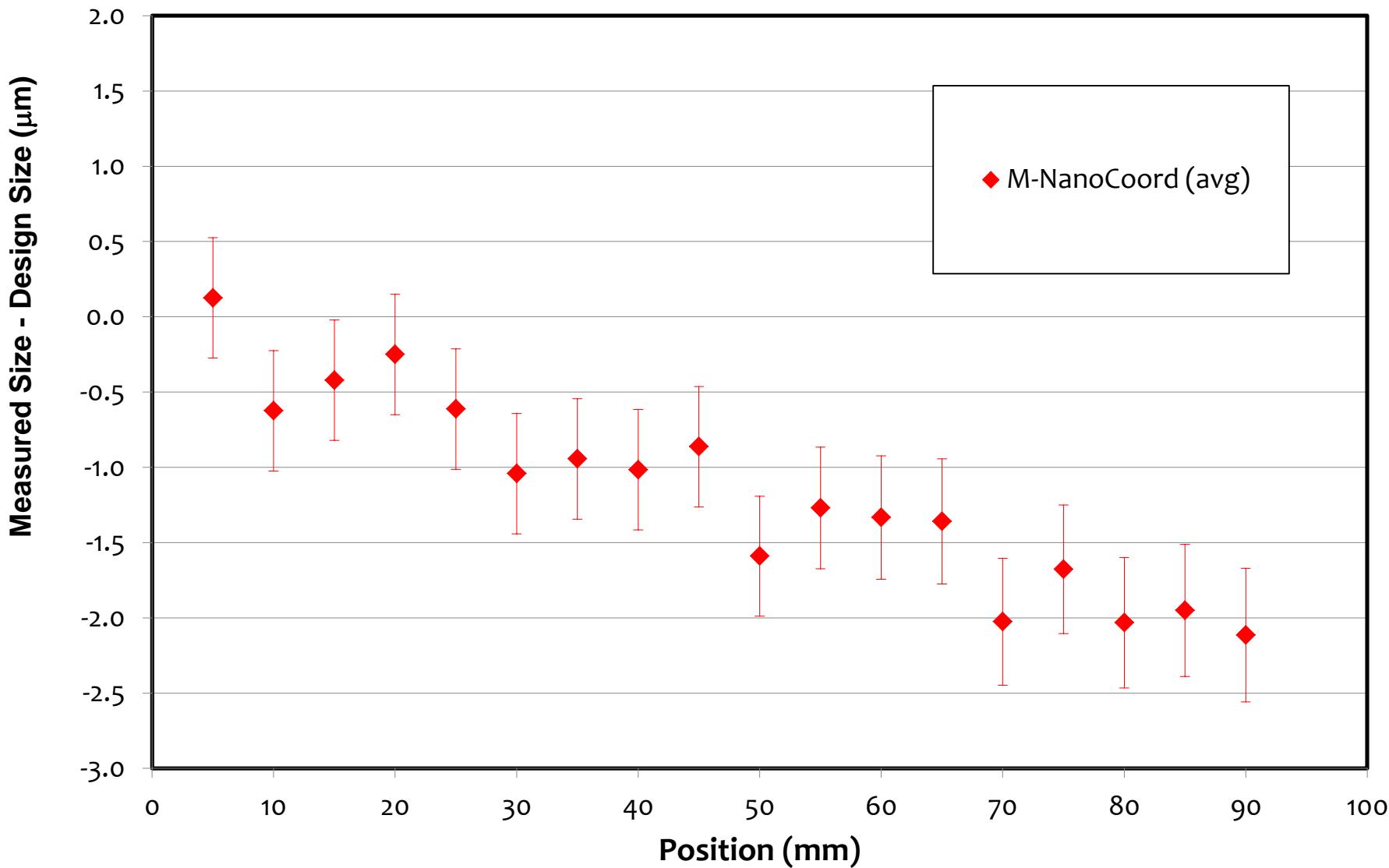
- Measurements were made using MEI's QV Ultra system (recently calibrated). Two sets of QV measurements were made using different measurement algorithms (rising edge and falling edge) with a 25 X objective.
- MEI measurements were made at the same nominal locations as Sandia measurements.

Measurements were made at the each cavity (1 ~ 19) along of the East most column, in the direction indicated.



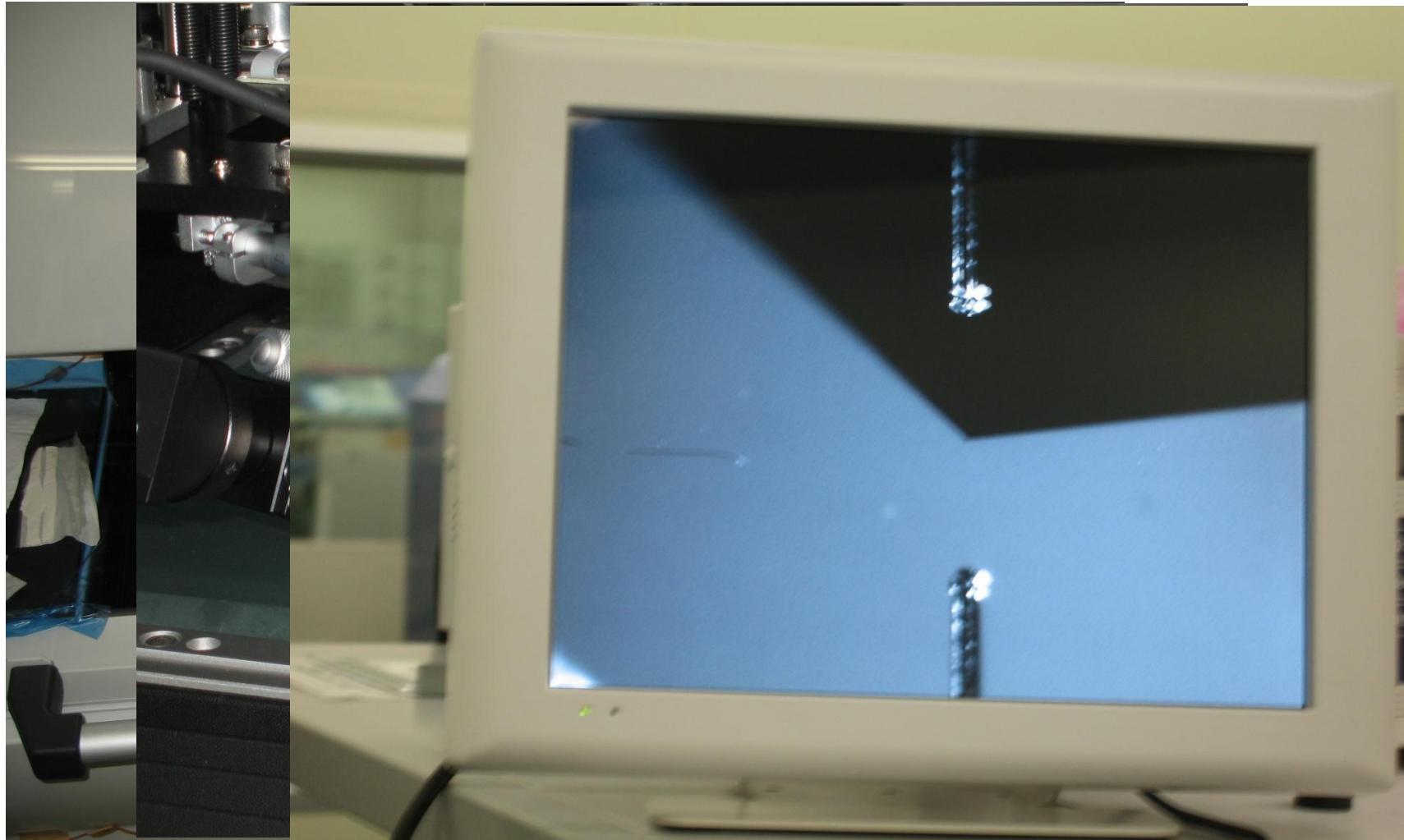
# QV Ultra measurement results

## M-NanoCoord Results



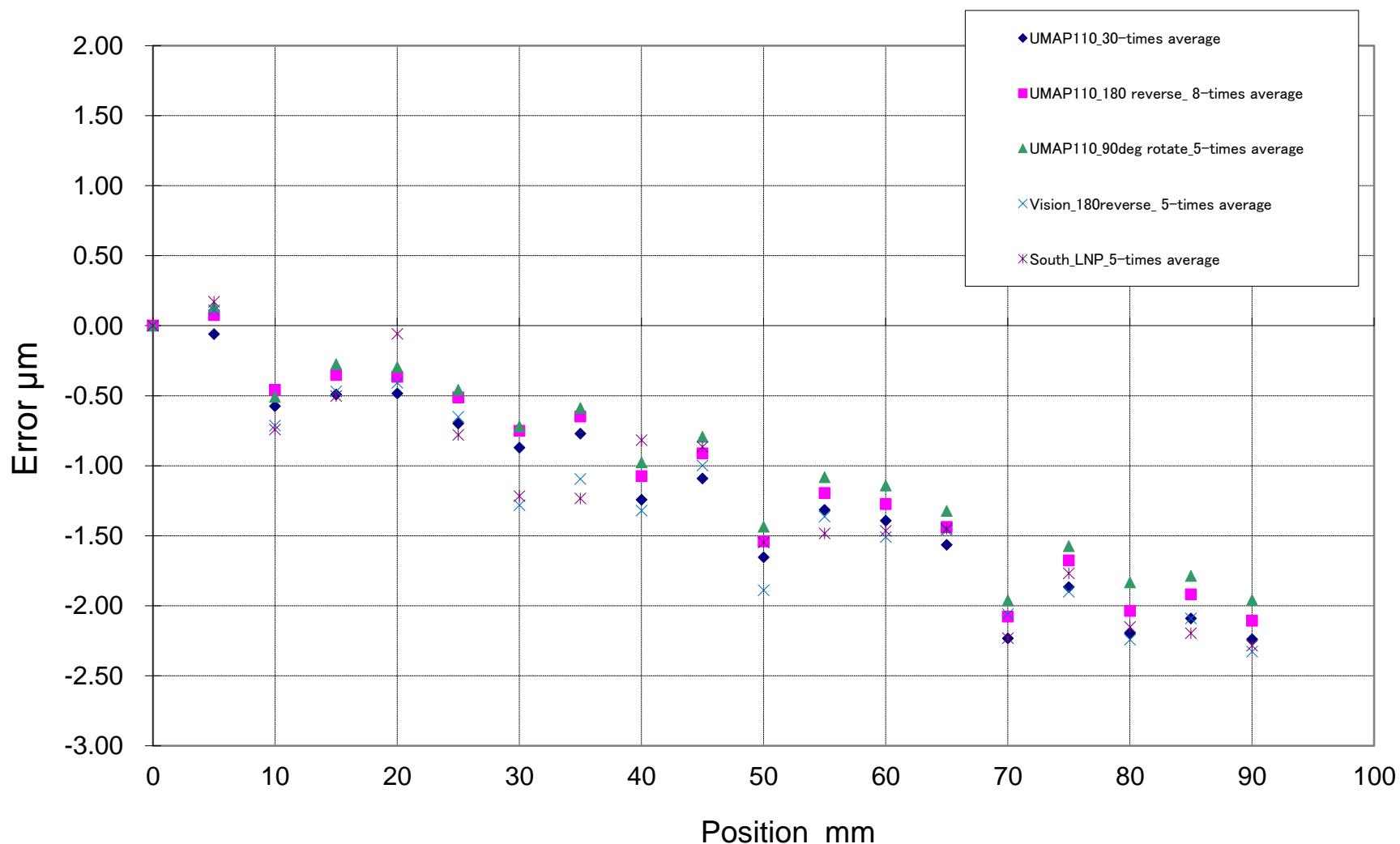
# Mitutoyo M-Nanocoord measurements

- Two different M-Nanocoords used
  - One uses both UMAP ultrasonic touch probe and optical vision probe
  - Other uses long-range ultralow force scanning probe (LNP probe)



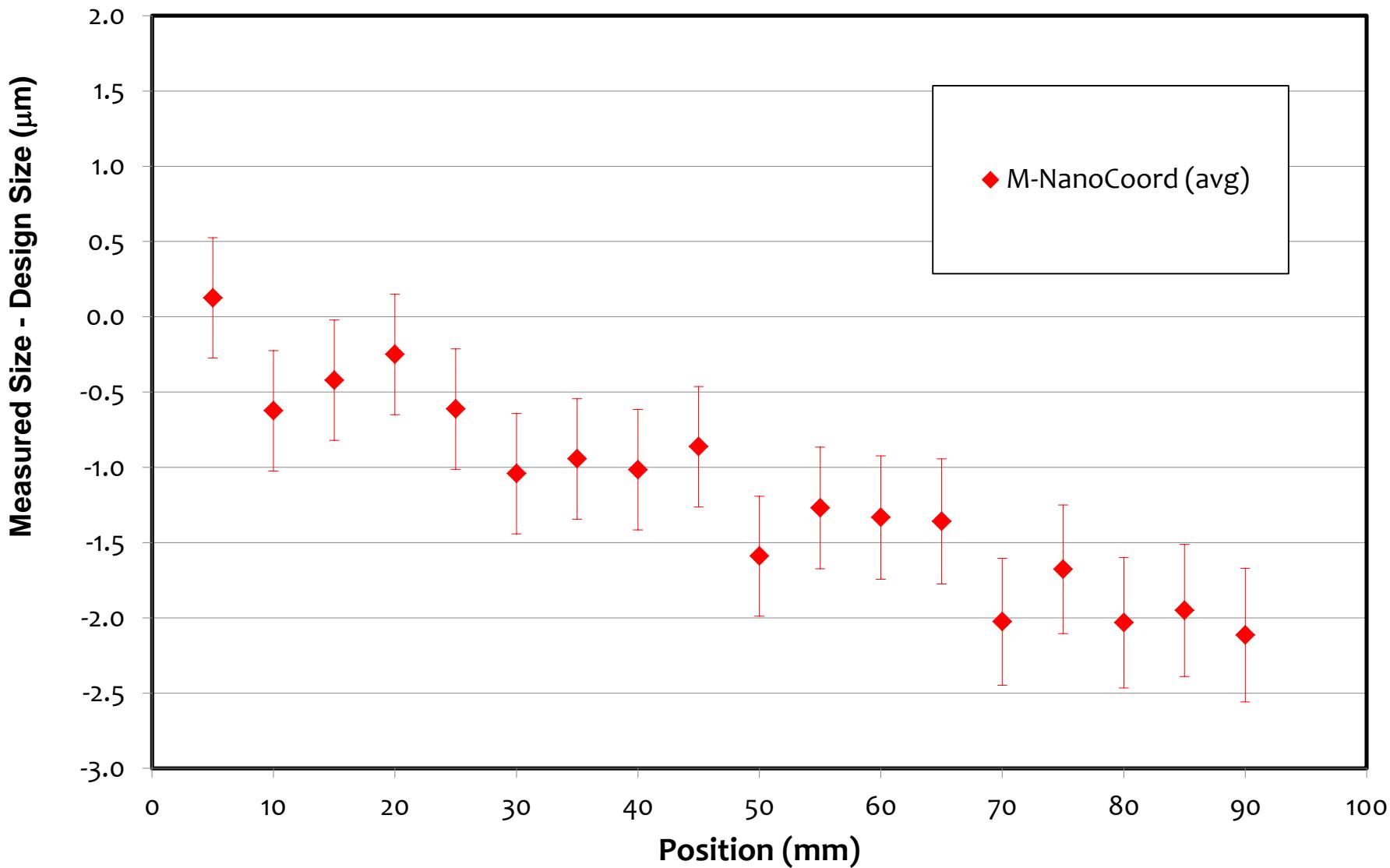
# M-Nanocoord intercomparison of probe systems

## Deviation from nominal



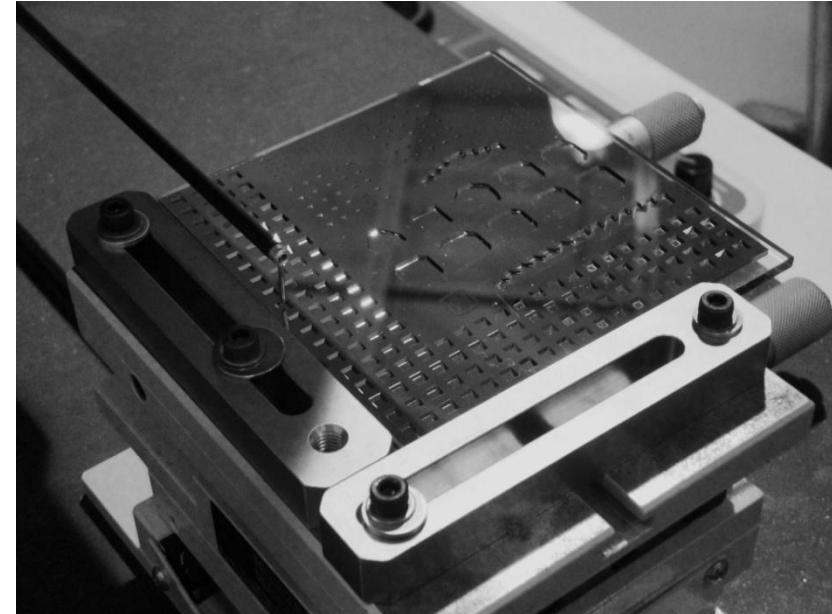
# M-Nanocoord results

## M-NanoCoord Results



# Setup

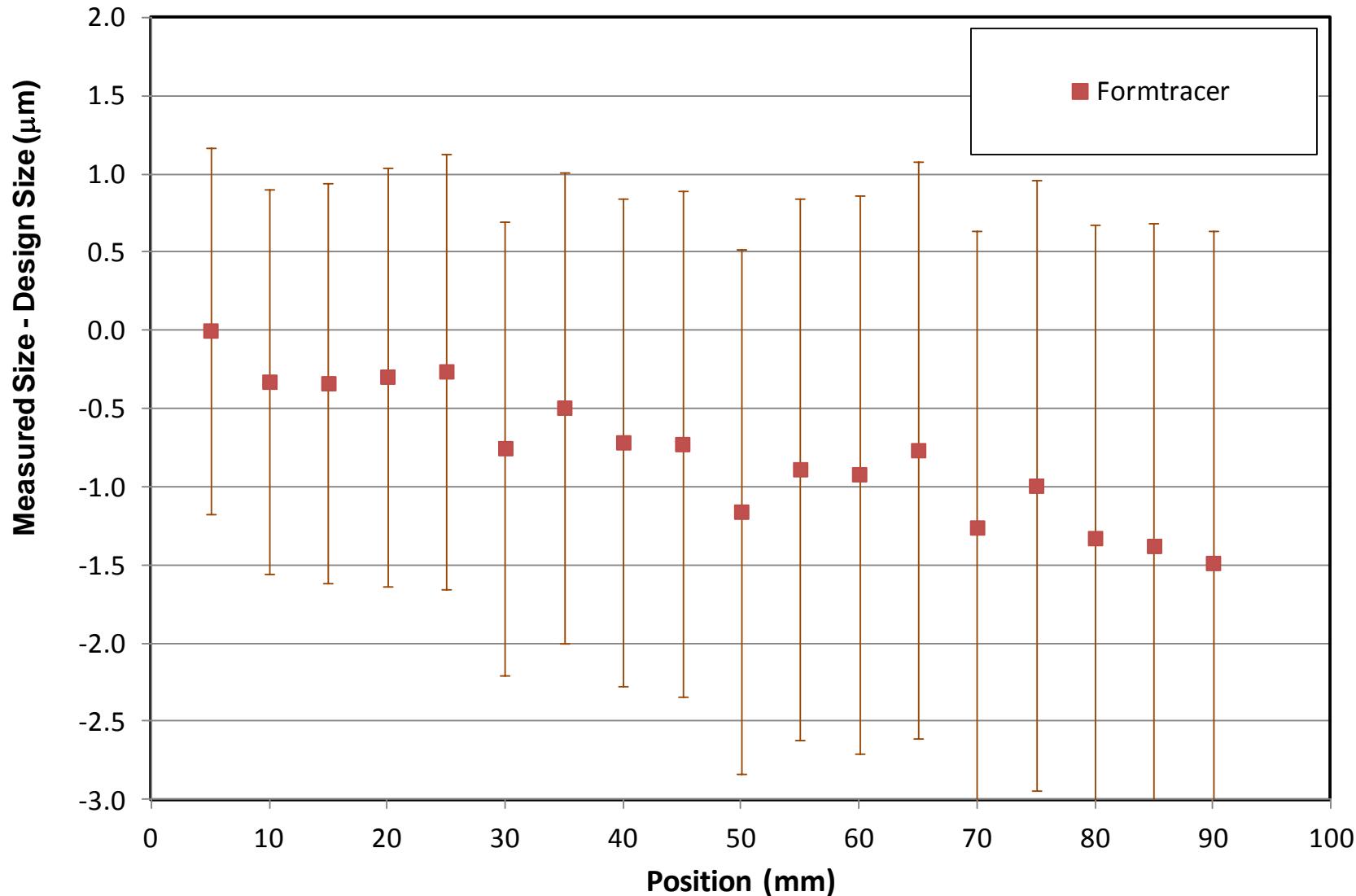
- A precision leveling table was used
  - Leveled to  $\frac{1}{2}$  micron manually
- Two brackets were mounted to the precision leveling table in an “L” shape to manually align the artifact into a fixed position
  - Further alignment would be done via software



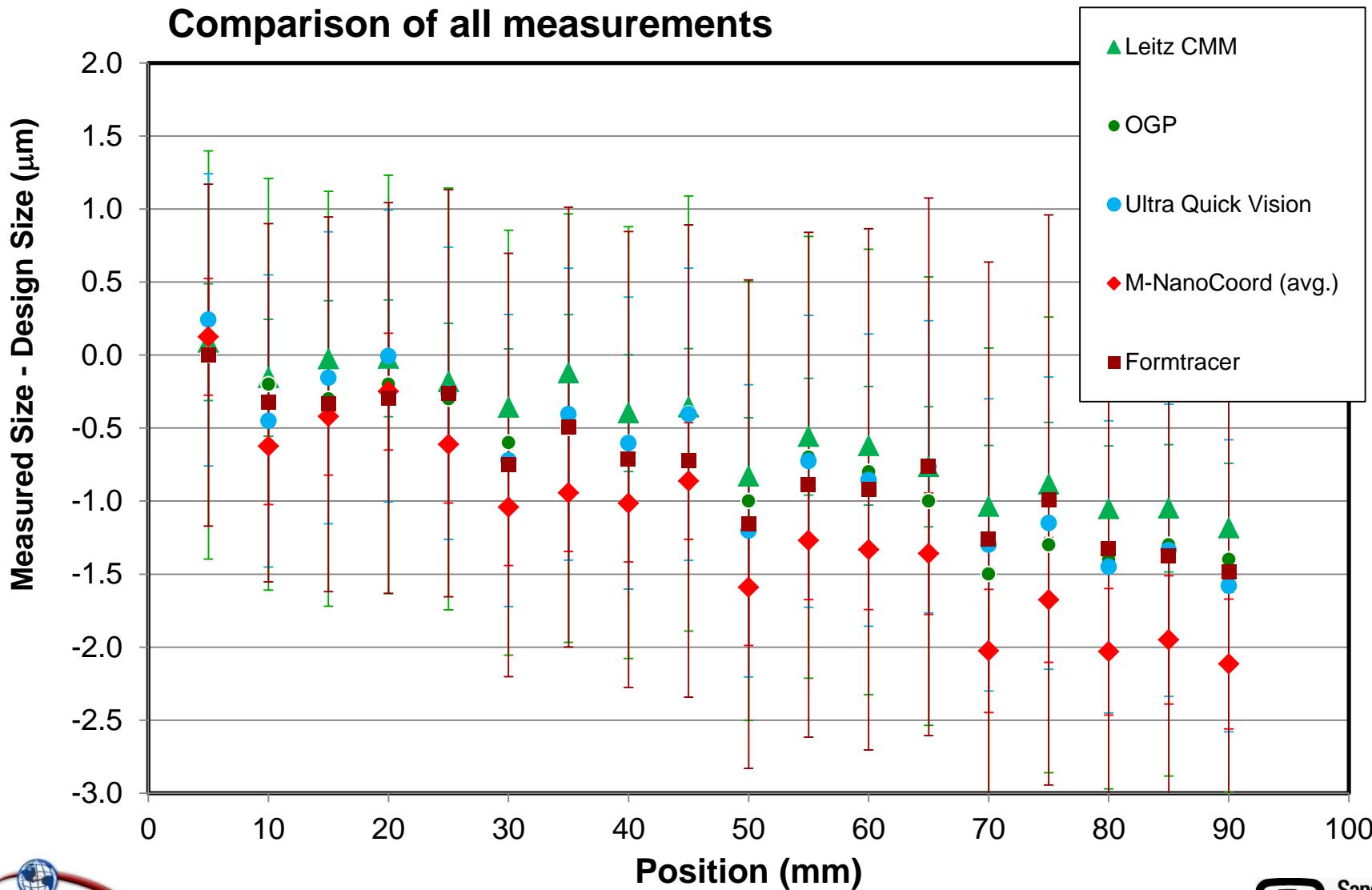
- Stylus used:
  - Number: 12AAD560
  - Stylus Tip Radius:  $2\mu\text{m}$
  - Stylus Tip Angle:  $60^\circ$
  - Stylus Tip Material: Diamond
- Stylus Measuring Speed: 0.1 mm/sec
- Measurement Force of Stylus: 0.75 mN

# Formtracer CS-3100 measurements

Formtracer results



# Intercomparison of all results





# Discussion & Conclusions

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- Manufacturing process still needs improvement
- Monte Carlo simulations show that even with rough sidewalls, expected measurement uncertainty of silicon artifact still > 2x better than for chrome-on-glass grid plates
- Common mechanical edge/optical edge verified with M-Nanocoord measurements
- Light level change has little effect on pitch measurement (very good contrast and sharp lines)



# Acknowledgments

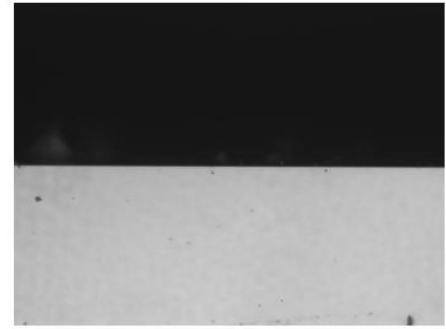
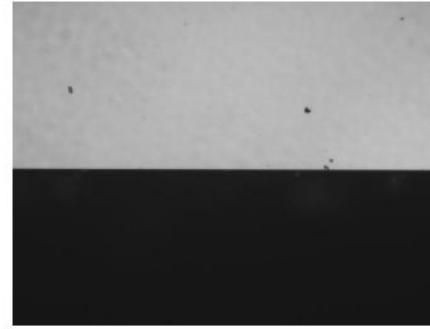
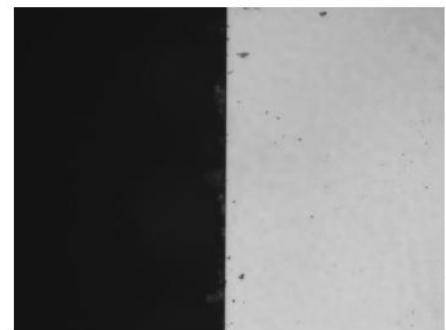
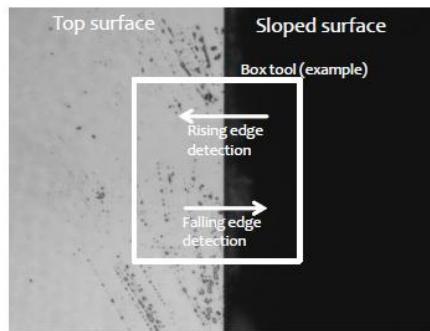
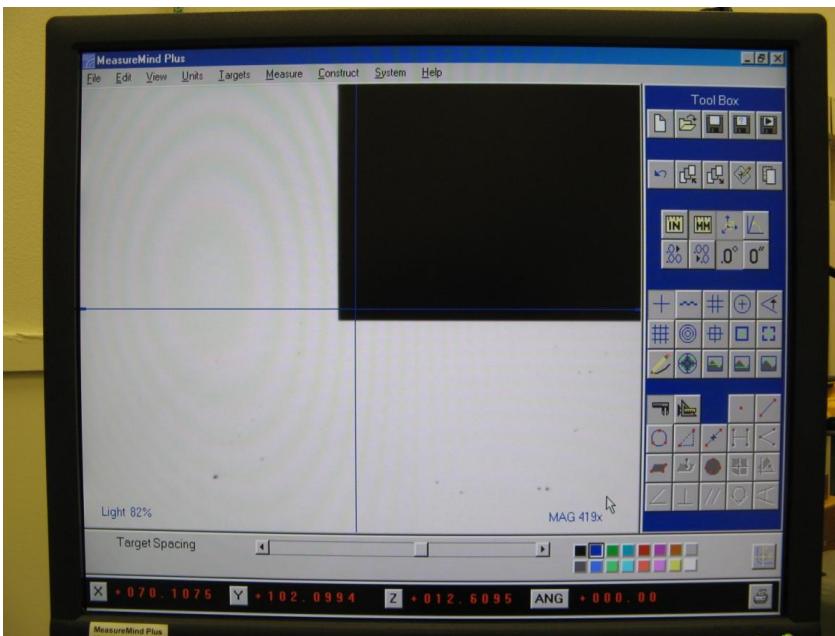
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- **Thanks for many technical contributions from: Todd Bauer, Margie Baca, Tony Bryce, Roger Burton, Andre Claudet, Ted Doiron, Orlando Espinosa, Harlan Gant, David Luck, Andy Oliver, Meghan Shilling, John Stoup, among others.**



# Backup slides

# Effects of Roughness on Vision System

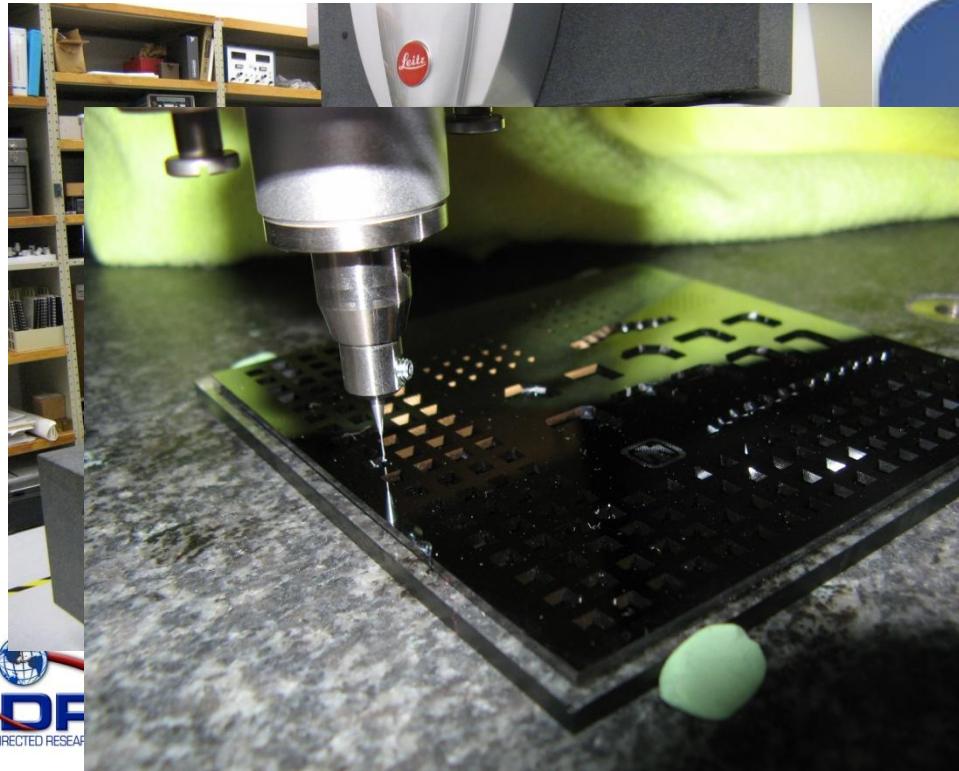


- Edges are very well defined with very good contrast, in spite of roughness on sidewalls



# Initial CMM & optical CMM measurements

- CMM is Leitz PMM-C-  
Infinity 12.10.6
- $MPE_e = (0.3 + L/1000) \mu\text{m}$
- OGP Smartscope APEX
- XY Accuracy  
 $(1.2 + 2L/1000) \mu\text{m}$

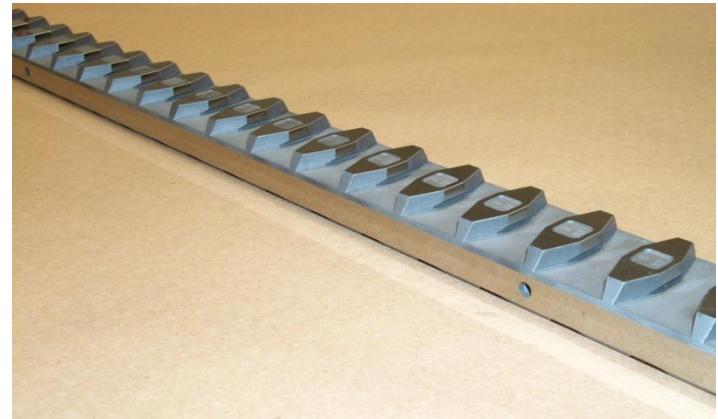






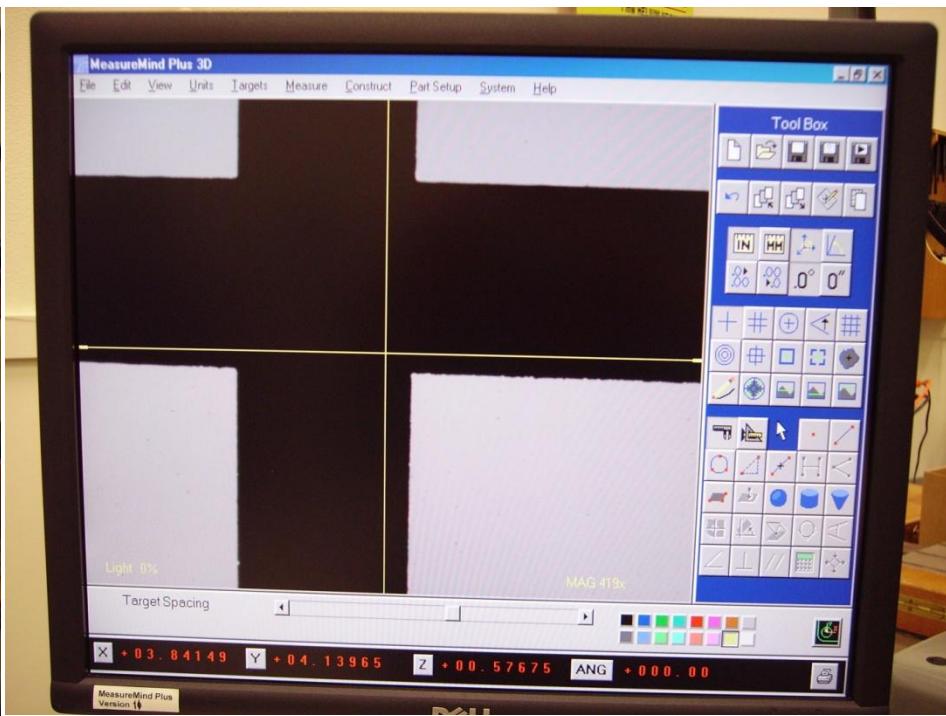
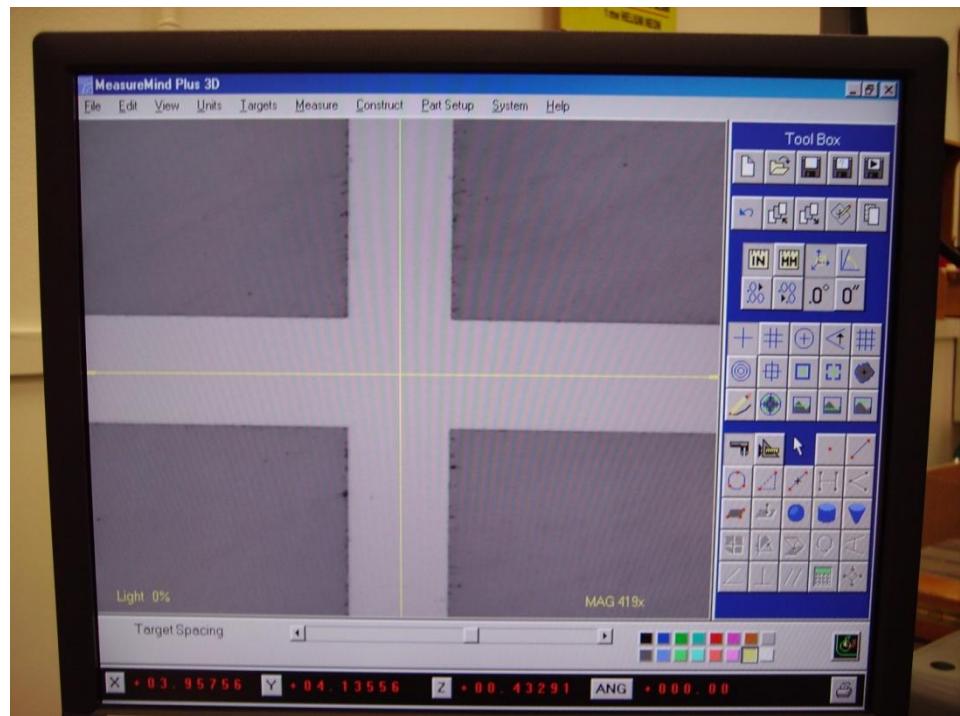
# Design Ideas for Calibration Artifact

- Fabricate artifact which contains miniature versions of “macro” metrology
- Step gage
  - 1D performance evaluation, 2/3D with repositioning
- Ball plate
  - 2D performance evaluation, 3D with repositioning
- Other objects for investigation





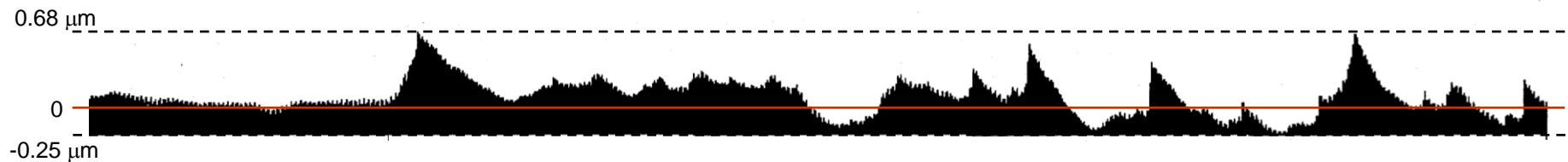
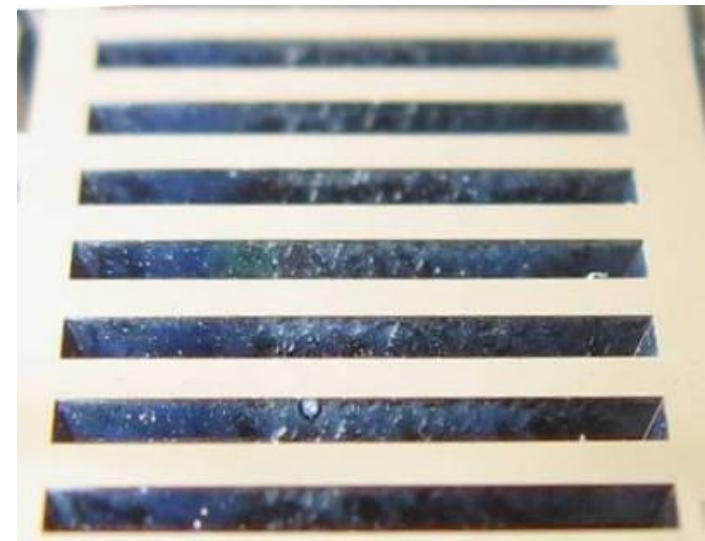
# Typical grid plates





# Manufacturing Issues

- Sidewalls are not smooth
- Appears that multiple crystal planes are being etched (misalignment?)
- Sidewalls may also be attacked by nitride removal process
- Effects of alternative removal processes studied





# Edge Measurement with UMAP

- Mitutoyo UMAP Ultra
- Contact measurements with probe
  - 30  $\mu\text{m}$  diameter
  - 2 mm stylus length
- Accuracy  
 $(1.2 + 3L/1000) \mu\text{m}$
- Repeatability  
 $s < 0.1 \mu\text{m}$



# UMAP Edge Measurement

